

Electrical and Computer Engineering Department

Written by:

Group K

Brandon Contreras

Daniele Ricciardelli

ECE 2200L:

Experiment Number 6

Bipolar Junction Transistor Biasing Circuits and Bias Point Stability
Represented to

Professor Mostafa Yazdy

Fall 2024

Thursday

October 10th, 2024

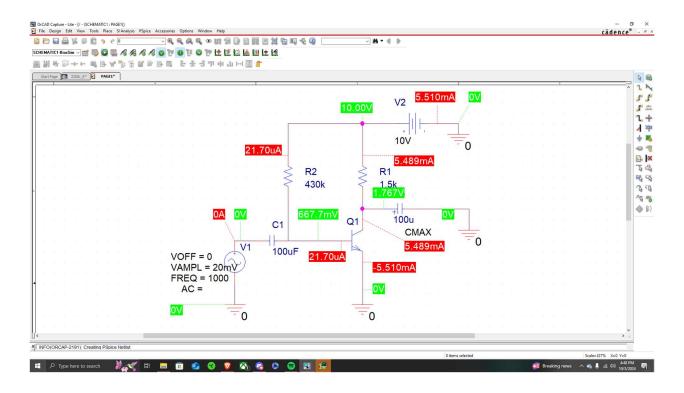
Background Information:

PNP transistor, also known as a Bipolar Junction Transistor (BJT), is a semiconductor device used in various applications. One of its primary functions is to amplify AC signals. To ensure stable operation, a BJT must be properly biased to maintain consistent values regardless of β .

Objective:

To study and experiment on three types of DC biasing circuits for BJTs, and compare the stability of the bias point in these circuits.

Pre-Lab:



$$I_B = rac{V_{cc} - V_{be}}{R_B} = rac{10 - V_{be}}{R_B}$$
 Assume $V_{be} = 0.7$ $I_C = eta \cdot I_B = rac{V_{cc} - 10}{R_C}$

$$I_C = eta \cdot I_B = rac{V_{cc} - 10}{R_C}$$

$$I_B = rac{10 - 0.7}{430 imes 10^3} pprox 22 \, \mu A \ I_C = eta \cdot I_B = 3.244 \, mA$$

$$I_C = eta \cdot I_B = 3.244 \, mA$$

$$egin{aligned} 10 - I_C R_C - V_{CE} &= 0 \quad \Rightarrow \quad V_{CE} = 10 - (3.244 imes 10^{-3}) (1.5 imes 10^3) \ V_{CE} &= 5.1337 \, V pprox 5.13 \, V \end{aligned}$$

$$I_B = rac{10 - 0.7}{430 imes 10^3} = 22\,\mu A$$

$$I_C = \beta \cdot I_B = 4.326 \, mA$$

$$V_{CE} = 10 - (4.326 imes 10^{-3})(1.5 imes 10^{3}) = 3.512\,V pprox 3.5\,V$$

B)

$$egin{aligned} ext{Percentage Change} &
ightarrow rac{ ext{New Value} - ext{Old Value}}{ ext{Old Value}} imes 100 \ I_C &
ightarrow rac{4.33\,mA - 3.24\,mA}{3.24\,mA} imes 100 pprox 33.64\% \ V_{CE} &
ightarrow rac{5.14 - 3.5}{5.14} imes 100 = 31.91\% \end{aligned}$$

$$egin{aligned} V_{eq} &= 10 \cdot rac{3.3k}{15k + 3.3k} = 1.80328\,V \ R_{eq} &= rac{15k \cdot 3.3k}{15k + 3.3k} = 2.70492\,k\Omega \ ext{Assume}\,V_{BE} &= 0.7 \end{aligned}$$

$$egin{align} ext{KVL:} & 1.8 - 2.7kI_B - V_{BE} - 200I_E = 0 \ & I_E = I_B + I_C \quad \Rightarrow \quad I_E = I_B (1 + eta) \ & 1.8 - 2.7kI_B - 0.7 - 200I_B (1 + eta) = 0 \ & I_B = 0.7 - 200I_B (1$$

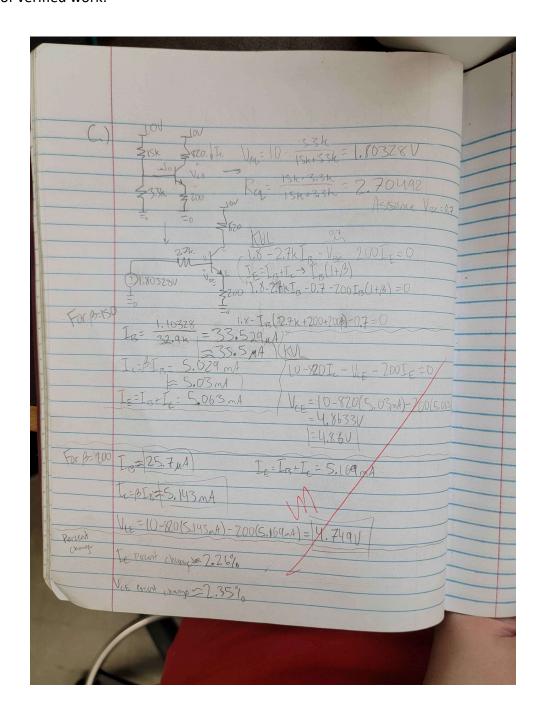
$$I_B = rac{1.10328}{32.9k} = 33.529\,\mu A pprox 33.5\,\mu A$$
 $I_C = eta I_B = 5.029\,m A pprox 5.03\,m A$ $I_E = I_B + I_C = 5.063\,m A$

$$ext{KVL:} \quad 10 - 820I_C = V_{CE} - 200I_E = 0$$
 $V_{CE} = 10 - 820(5.03\,mA) - 200(5.063\,mA) = 4.8633\,V pprox 4.86\,V$

$$I_B = 25.7\,\mu A$$
 $I_E = I_B + I_C = 5.169\,mA$ $I_C = eta I_B = 5.143\,mA$ $V_{CE} = 10 - 820(5.143\,mA) - 200(5.169\,mA) = 4.749\,V$

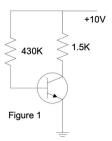
 I_C percent change pprox 2.26% V_{CE} percent change pprox 2.35%

Proof of verified work:

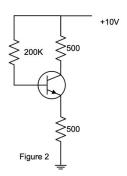


Lab Report:

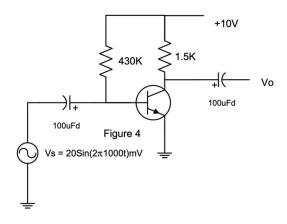
1. <u>Figure 1:</u>



2. *Figure 2:*



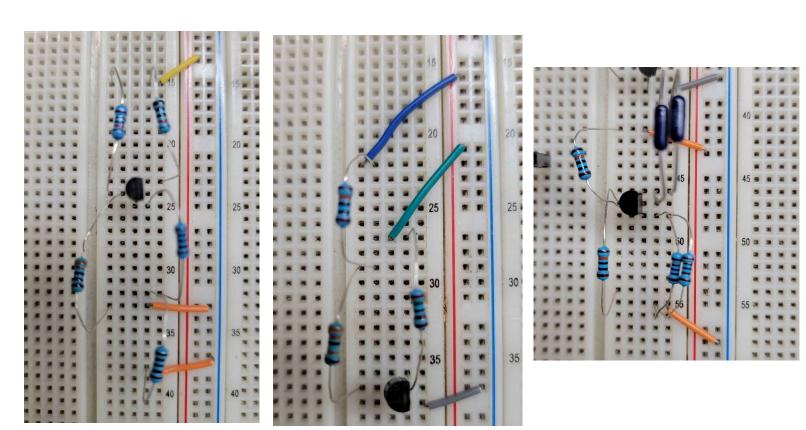
3. <u>Figure 3:</u>



Data tables:

				Q1=3904	1		
				Q2=2222			
Figure1	Vb		Vc		Ic(mA)	Ib/mA)	Beta
Q1	VD	0.72	4.74E+00		Ic(mA) 3.51F+00	lb(mA) 0.021581	
Q2			1.88E+00			0.021698	
Figure2	Vb		Vc	Ve	Ic(mA)	lb(uA)	Beta
Q1	VD	3.44	7.25	2.75		50.94	
Q2		4.28	6.35	3.64			1.67E-01
Figure3	Vb		Vc	Ve	Ic(mA)	lb(uA)	Beta
Q1		1.74	5.80E+00	1.04	5.12E+00	32.63	1.57E-01
Q2		1.76	5.48	1.115	5.51E+00	28.3	1.95E-01

Constructed circuits:



Conclusion:

In this Experiment, we build the three circuits physically in the lab. Each circuit had different number of resistors to see which one will give us the most stability regardless of the value of β . In the last figure, we created an AC Amplifier using a BJT and 4 resistors, and 2 coupling capacitors. We also plotted V_{in} and V_{out} vs time, as well as V_s and V_{in} vs time on the oscilloscope to calculate the gain.

Post Lab:

- For the circuits in Figures 1, 2 and 3, calculate and tabulate Ic, Ib and Beta for two different BJT's. → Done in the lab report chart
- 2. Compare the measurements for Vbe, Vce, Ic and Ib (in Figure 3) to the simulation results from prelab of experiment 5 (the same circuit).

After Implementing the above figure on the breadboard, we got:

$$V_{BE} = 0.7V$$

$$V_E = 1.08V$$

$$V_c = 5.5 V$$

$$I_{15K} \approx 10I_B = \frac{V_{CC} - V_B}{15k\Omega} = \frac{10 - 1.7}{15k} = 5.53 \times 10^{-4} A = 0.55 \, mA$$

•
$$I_B = 55.3 \, \mu A$$

•
$$I_c = \frac{V_{CC} - V_C}{820\Omega} = \frac{10 - .5}{820} = 5.49 \text{ mA}$$

•
$$I_E = \frac{1.08V}{200\Omega} = 5.4mA$$

•
$$I_C \approx I_E$$